

UNISONIC TECHNOLOGIES CO., LTD

UTT4407 Preliminary

Power MOSFET

P-CHANNEL ENHANCEMENT MODE POWER MOSFET

■ DESCRIPTION

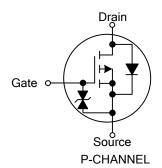
The UTC **UTT4407** is a P-channel enhancement mode power MOSFET using UTC's advanced trench technology to provide customers with a minimum on-state resistance and extremal low gate charge with a 25V gate rating

The UTC **UTT4407** is universally applied in PWM or used as a oad switch



- * $V_{DS(V)} = -30V$
- * $I_D = -12A (V_{GS} = -20V)$
- * $R_{DS(ON)}$ < 13m Ω @ V_{GS} = -20V, I_D = -10A $R_{DS(ON)}$ < 14m Ω @ V_{GS} = -4.5V, I_D = -10A

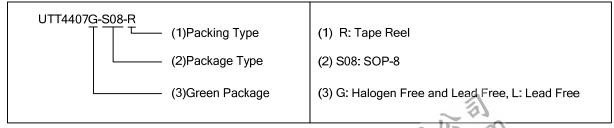




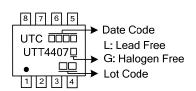
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment							Doolsing		
Lead Free	Halogen Free	Package	1	2	3	4	5	6	7	8	Packing	
UTT4407L-S08-R	UTT4407G-S08-R	SOP-8	S	S	S	G	D	D	D	D	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



■ MARKING



SOP-8

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■ **ABSOLUTE MAXIMUM RATINGS** (T_A = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT		
Drain-Source Voltage		V_{DSS}	-30	V		
Gate-Source Voltage			V_{GSS}	±25	V	
Drain Current	Continuous/Note 2)	T _A = 25°C	- I _D	-12		
	Continuous(Note 2)	T _A = 70°C		-10	Α	
	Pulsed (Note 3)		I _{DM}	-60		
Power Dissipation (Note 2) $\frac{T_A = 25^{\circ}C}{T_A = 70^{\circ}C}$		D	3	W		
		T _A = 70°C	P _D	2.1	VV	
Junction Temperature			T_J	+150	°C	
Storage Temperature			T _{STG}	-55 ~ + 150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Device mounted on 1in² FR-4 board with 2oz. Copper, t = 10sec.
- 3. Repetitive rating, pulse width limited by junction temperature.

■ THERMAL CHARACTERISTICS (T_A = 25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note)	θ_{JA}	75	°C/W

Note: Device mounted on 1in² FR-4 board with 2oz. Copper, t = 10sec.

■ ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise noted)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT			
OFF CHARACTERISTICS					_					
Drain-Source Breakdown Voltage		BV _{DSS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-30			V			
Drain-Source Leakage Current		I _{DSS}	V _{DS} =-24V,V _{GS} =0 V			-1				
			V _{DS} =-24V,V _{GS} =0 V,T _J =55°C			-5	μΑ			
Gate- Source Leakage Current	Forward	I _{GSS}	V_{GS} =+25 V , V_{DS} =0 V			+100				
	Reverse		V _{GS} =-25V,V _{DS} =0V			-100	μA			
ON CHARACTERISTICS										
Gate Threshold Voltage		$V_{GS(TH)}$	V _{DS} =V _{GS} , I _D =-250 μA	-1.7	-2.5	-3	V			
Drain-Source On-State Resistance			V _{GS} =-10V, I _D =-10A			14	mΩ			
			V _{GS} =-10V,I _D =-10A,T _J =125°C		15	19	mΩ			
		R _{DS(ON)}	V _{GS} =-20V, I _D =-10A		10	13	mΩ			
			V_{GS} =-4.5V, I_{D} =-10A		24		mΩ			
DYNAMIC PARAMETERS										
nput Capacitance		C _{ISS}			2076	2500				
Output Capacitance		Coss	V _{DS} =-15 V, V _{GS} =0V, f=1MHz		503		pF			
Reverse Transfer Capacitance		C _{RSS}			302					
Gate Resistance		R_{g}	V_{DS} =0V, V_{GS} =0V, f=1MHz		2	3	Ω			
SWITCHING PARAMETERS										
Total Gate Charge		Q_G	V _{DS} =-15V,V _{GS} =-10V,		37.2	45	nC			
Gate Source Charge		Q_GS	I _D =-12A		7					
Gate Drain Charge		Q_GD	ID IZA		10.4					
Turn-ON Delay Time		t _{D(ON)}		0	12.4					
Turn-ON Rise Time		t _R	V _{DS} =-15V, V _{GS} =-10V,		8.2		ns			
Turn-OFF Delay Time		t _{D(OFF)}	R_L =1.25Ω, R_{GEN} =3Ω	0	25.6					
urn-OFF Fall-Time		t_{F}	L SP C	12						
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS										
Drain-Source Diode Forward Voltage		V_{SD}	I_S =-1A, V_{GS} =0V		-0.72	-1	V			
Maximum Continuous Drain-Source Diode		I _S	9 194 1109			-4.2	Α			
Forward Current		-4,3	43 511,			-4.4	^			
Body Diode Reverse Recovery Time		t _{in}	l _F =-12 A, dl/dt=100A/μs	33	40	ns				
Body Diode Reverse Recovery Ch	narge	Qm	l _F =-12A, dI/dt=100A/μs		23		nC			

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